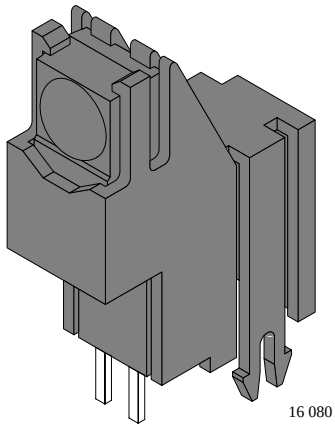
Photo Modules for PCM Remote Control Systems

Available types for different carrier frequencies

Type	fo	Type	fo
TSOP4830WE1	30 kHz	TSOP4833WE1	33 kHz
TSOP4836WE1	36 kHz	TSOP4837WE1	36.7 kHz
TSOP4838WE1	38 kHz	TSOP4840WE1	40 kHz
TSOP4856WE1	56 kHz		

Description

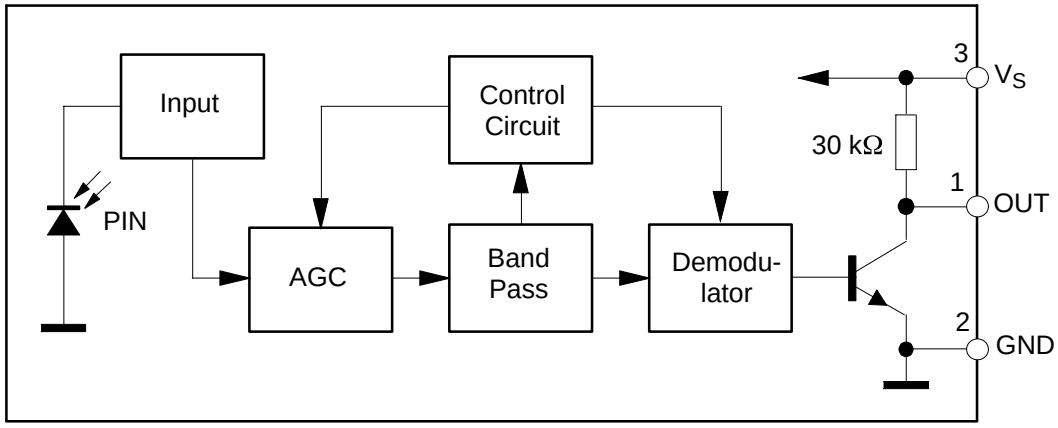
The TSOP48..WE1 – series are miniaturized receivers for infrared remote control systems. PIN diode and preamplifier are assembled on lead frame, the epoxy package is designed as IR filter.
The demodulated output signal can directly be decoded by a microprocessor. TSOP48..WE1 is the standard IR remote control receiver series, supporting all major transmission codes.


16 080

Features

- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against electrical field disturbance
- TTL and CMOS compatibility
- Output active low
- Low power consumption
- High immunity against ambient light
- Continuous data transmission possible (800 bit/s)
- Suitable burst length ≥10 cycles/burst

Block Diagram



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Absolute Maximum Ratings

T_{amb} = 25°C

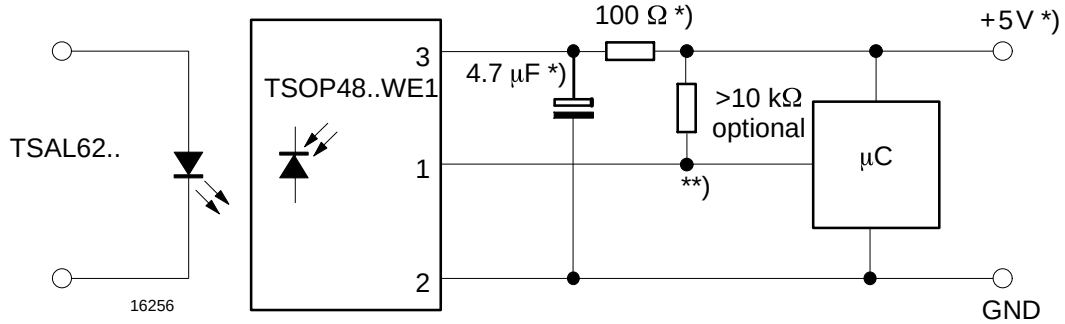
Parameter	Test Conditions	Symbol	Value	Unit
Supply Voltage	(Pin 2)	V_S	–0.3...6.0	V
Supply Current	(Pin 2)	I_S	5	mA
Output Voltage	(Pin 1)	V_O	–0.3...6.0	V
Output Current	(Pin 1)	I_O	5	mA
Junction Temperature		T_j	100	˚C
Storage Temperature Range		T_{stg}	–25...+85	˚C
Operating Temperature Range		T_{amb}	–25...+85	˚C
Power Consumption	(T_{amb} ≦ 85 ˚C)	P_{tot}	50	mW
Soldering Temperature	t ≦ 10 s, 1 mm from case	T_{sd}	260	˚C

Basic Characteristics

T_{amb} = 25°C

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Supply Current (Pin 3)	V_S = 5 V, E_v = 0	I_{SD}	0.8	1.1	1.5	mA
	V_S = 5 V, E_v = 40 klx, sunlight	I_{SH}		1.4		mA
Transmission Distance	E_v = 0, test signal see fig.7, IR diode TSAL6200, I_F = 250 mA	d		35		m
Supply Voltage		VS	4.5		5.5	V
Output Voltage Low (Pin 3)	I_{OSL} = 0.5 mA,E_e = 0.7 mW/m^2	V_{OSL}			250	mV
Irradiance (56 kHz)	Pulse width tolerance: $t_{pi} - 5/f_o <$ $t_{po} < t_{pi} + 6/f_o$, test signal see fig.7	$E_{e\ min}$		0.3	0.6	mW/m^2
Irradiance (30–40 kHz)		$E_{e\ min}$		0.2	0.4	mW/m^2
Irradiance	$t_{pi} - 5/f_o < t_{po} < t_{pi} + 6/f_o$	$E_{e\ max}$	30			W/m^2
Directivity	Angle of half transmission distance	$\varphi_{1/2}$		±45		deg

Application Circuit



*) recommended to suppress power supply disturbances
**) The output voltage should not be hold continuously at a voltage below 3.3V by the external circuit.

Suitable Data Format

The circuit of the TSOP48..WE1 is designed in that way that unexpected output pulses due to noise or disturbance signals are avoided. A bandpassfilter, an integrator stage and an automatic gain control are used to suppress such disturbances.
The distinguishing mark between data signal and disturbance signal are carrier frequency, burst length and duty cycle.

The data signal should fullfill the following condition:

- Carrier frequency should be close to center frequency of the bandpass (e.g. 38kHz).
- Burst length should be 10 cycles/burst or longer.
- After each burst which is between 10 cycles and 70 cycles a gap time of at least 14 cycles is necessary.
- For each burst which is longer than 1.8ms a corresponding gap time is necessary at some time in the data stream. This gap time should be at least 4 times longer than the burst.
- Up to 800 short bursts per second can be received continuously.

Some examples for suitable data format are:
NEC Code, Toshiba Micom Format, Sharp Code, RC5 Code, RC6 Code, R–2000 Code.

When a disturbance signal is applied to the TSOP48..WE1 it can still receive the data signal. However the sensitivity is reduced to that level that no unexpected pulses will occure.

Some examples for such disturbance signals which are suppressed by the TSOP48..WE1 are:

- DC light (e.g. from tungsten bulb or sunlight)
- Continuous signal at 38kHz or at any other frequency
- Signals from fluorescent lamps with electronic ballast with high or low modulation (see Figure A or Figure B).

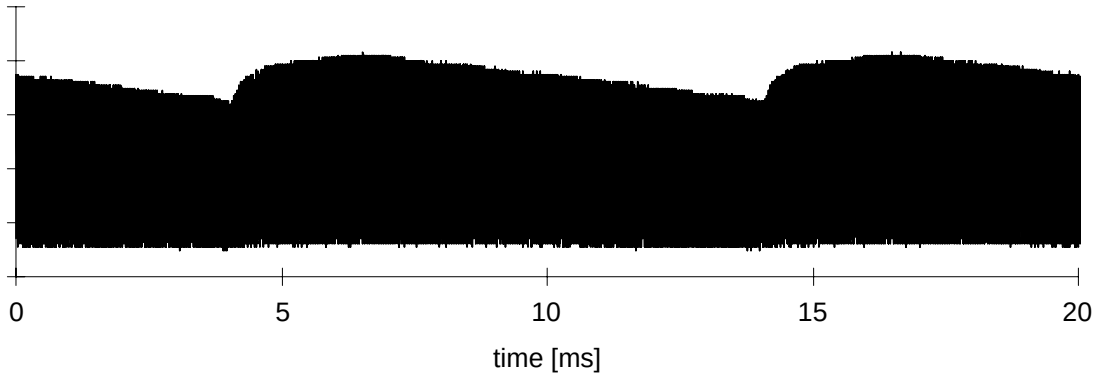


Figure A: IR Signal from Fluorescent Lamp with low Modulation

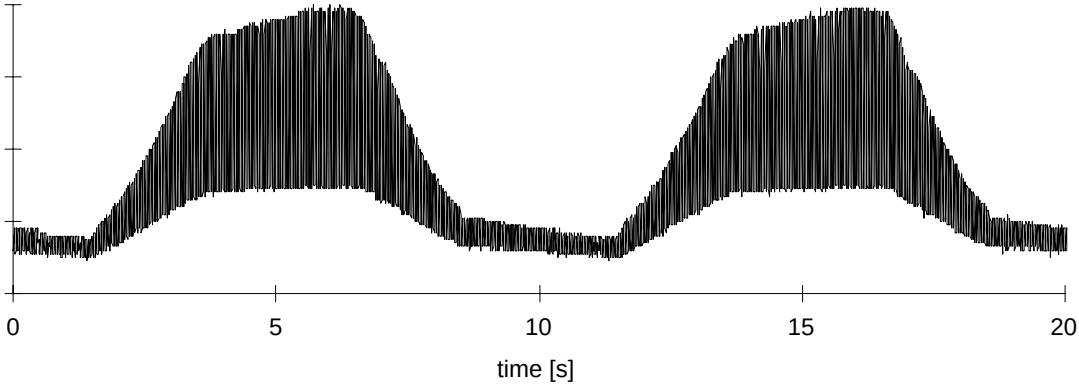


Figure B: IR Signal from Fluorescent Lamp with high Modulation

Typical Characteristics (T_{amb} = 25°C unless otherwise specified)

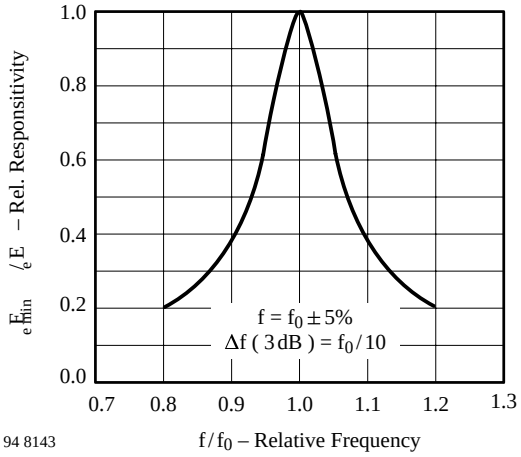


Figure 1. Frequency Dependence of Responsivity

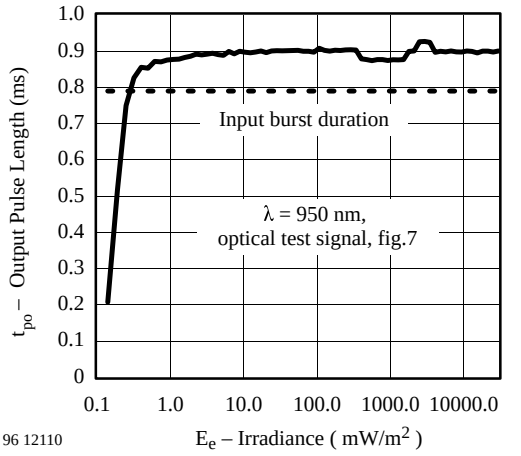


Figure 2. Sensitivity in Dark Ambient

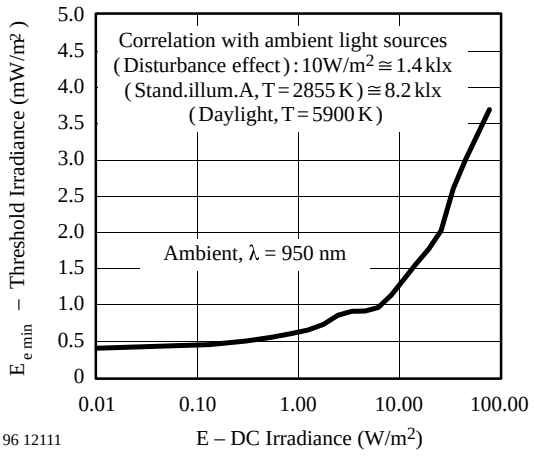


Figure 3. Sensitivity in Bright Ambient

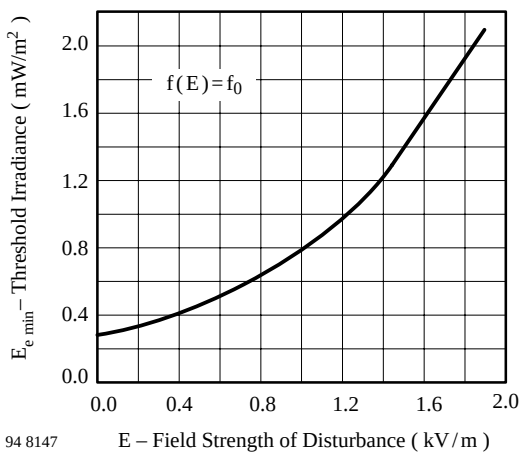


Figure 4. Sensitivity vs. Electric Field Disturbances

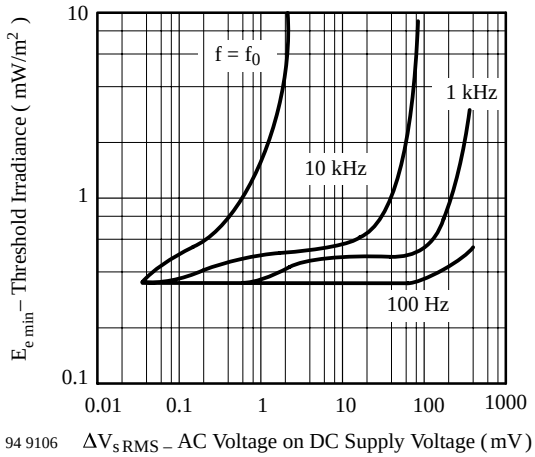


Figure 5. Sensitivity vs. Supply Voltage Disturbances

Figure 6. Sensitivity vs. Ambient Temperature

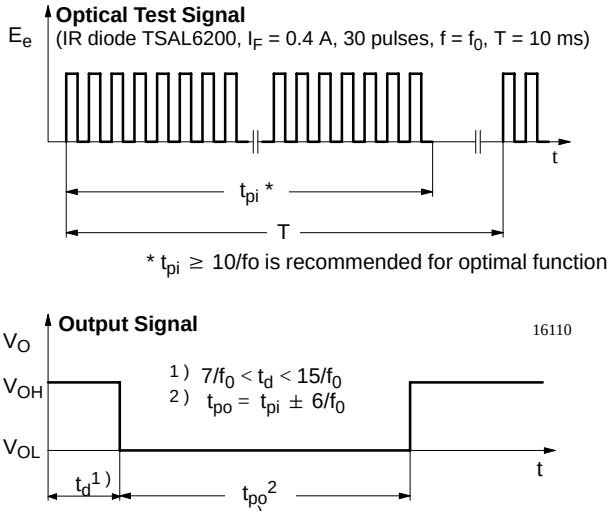


Figure 7. Output Function

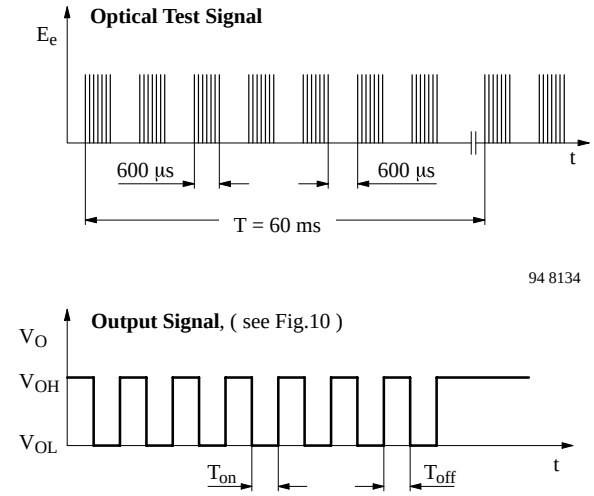


Figure 8. Output Function

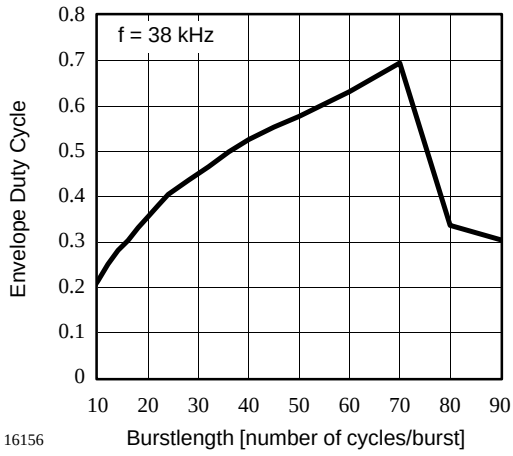


Figure 9. Max. Envelope Duty Cycle vs. Burstlength

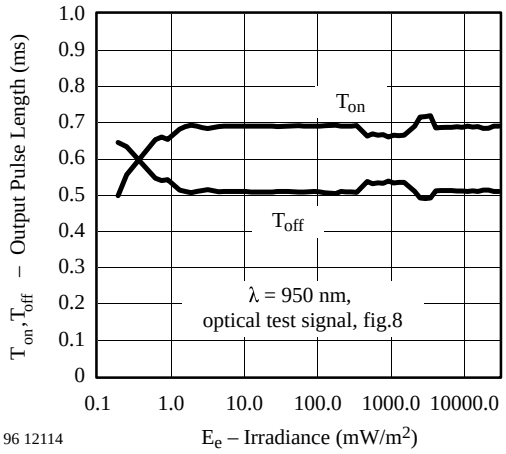


Figure 10. Output Pulse Diagram

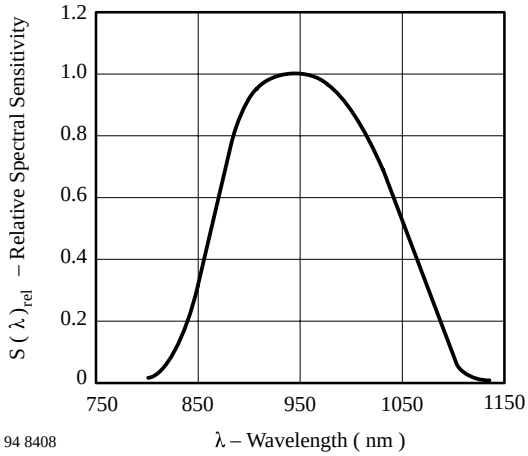


Figure 11. Relative Spectral Sensitivity vs. Wavelength

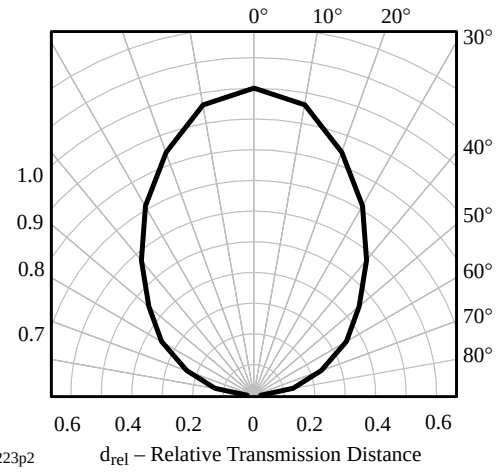
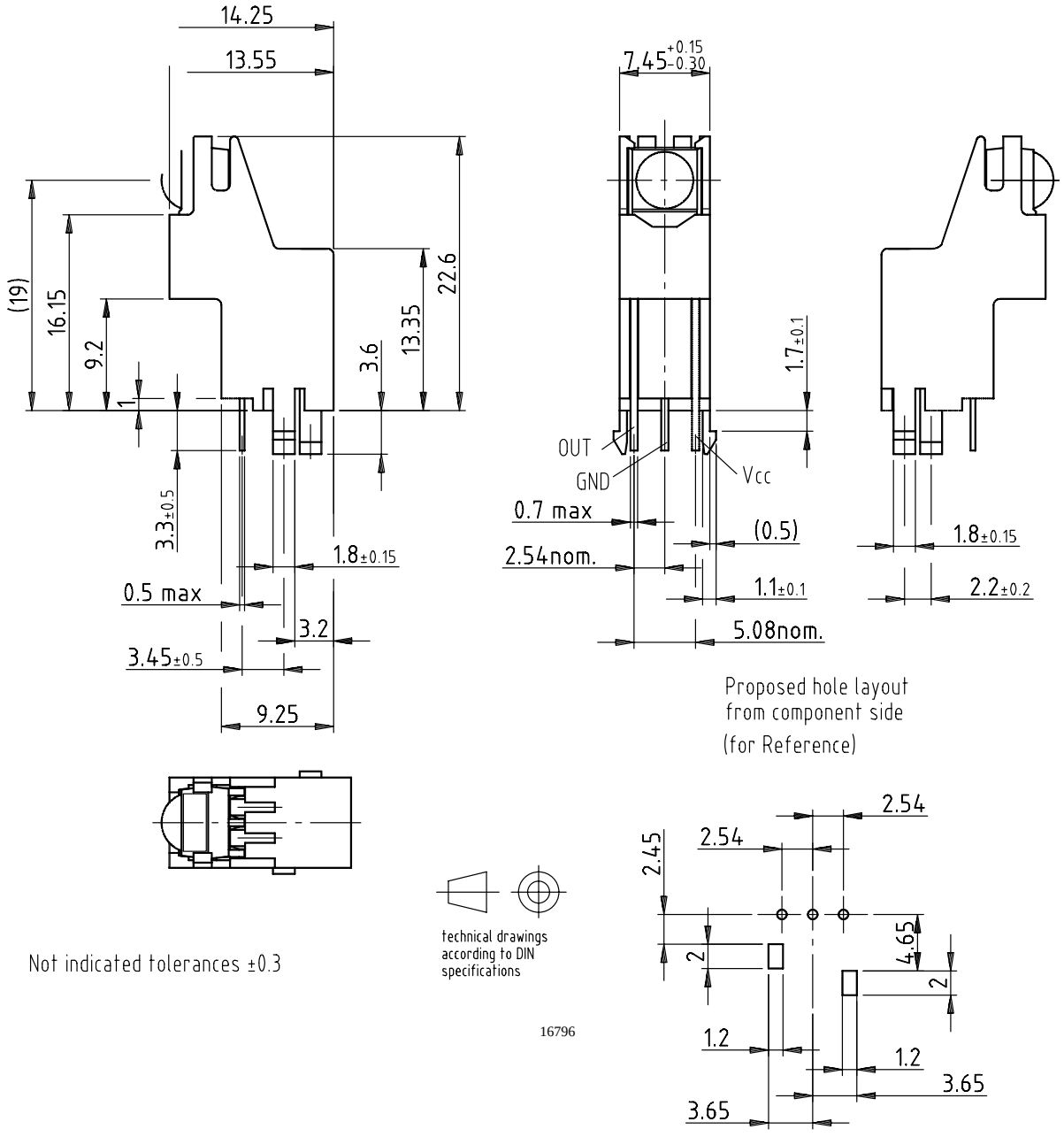


Figure 12. Directivity

Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.
Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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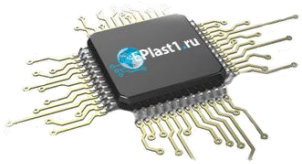
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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